

High-speed double diode Rev. 3 — 29 June 2010

Product data sheet

Product profile

1.1 General description

Two high-speed switching diodes fabricated in planar technology, and encapsulated in a small SOT143B Surface-Mounted Device (SMD) plastic package. The diodes are not connected.

1.2 Features and benefits

■ High switching speed: $t_{rr} \le 6$ ns

Reverse voltage: V_R ≤ 60 V

Repetitive peak reverse voltage: V_{RRM} ≤ 60 V Repetitive peak forward current: I_{FRM} ≤ 600 mA

AEC-Q101 qualified

Small SMD plastic package

1.3 Applications

High-speed switching in e.g. surface-mounted circuits

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _F	forward current		[1][2]	-	200	mA
I _R	reverse current	$V_{R} = 60 \text{ V}$	-	-	100	nA
V_R	reverse voltage		-	-	60	V
t _{rr}	reverse recovery time		[3] _	-	6	ns

^[1] Single diode loaded.



^[2] Device mounted on an FR4 Printed-Circuit Board (PCB).

^[3] When switched from I_F = 400 mA to I_R = 400 mA; R_L = 100 Ω ; measured at I_R = 40 mA.

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2. Pinning information

Table 2. Pinning

Table 2.	Finning		
Pin	Description	Simplified outline	Graphic symbol
1	cathode (diode 1)		
2	cathode (diode 2)	4 3	4 3
3	anode (diode 2)		
4	anode (diode 1)	1 2	
			1 2
			006aab100

3. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
BAS56	-	plastic surface-mounted package; 4 leads	SOT143B			

4. Marking

Table 4. Marking codes

Type number	Marking code ^[1]
BAS56	*L5

- [1] * = -: made in Hong Kong
 - * = p: made in Hong Kong
 - * = t: made in Malaysia
 - * = W: made in China

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5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{RRM}	repetitive peak reverse		-	60	V
	voltage		[1] -	120	V
V_R	reverse voltage		-	60	V
			[1] -	120	V
l _F	forward current		[2][3]	200	mA
			[2][4]	150	mA
I _{FRM}	repetitive peak forward		<u>[3]</u> _	600	mA
	current		[4] -	430	mA
I _{FSM}	non-repetitive peak forward current	square wave	<u>[5]</u>		
		t _p = 1 μs	-	9	Α
		t _p = 100 μs	-	3	Α
		$t_p = 10 \text{ ms}$	-	1.7	Α
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2] -	250	mW
Tj	junction temperature		-	150	°C
T _{stg}	storage temperature		-65	+150	°C

^[1] Series connection.

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	<u>[1]</u> -	-	500	K/W
$R_{th(j-t)}$	thermal resistance from junction to tie-point		-	-	360	K/W

^[1] Device mounted on an FR4 PCB.

^[2] Device mounted on an FR4 PCB.

^[3] Single diode loaded.

^[4] Double diode loaded.

^[5] $T_j = 25$ °C prior to surge.

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7. Characteristics

Table 7. Characteristics

 $T_i = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{F}	forward voltage	$I_F = 200 \text{ mA}$	<u>[1]</u> -	-	1	V
I _R	reverse current	$V_R = 60 \text{ V}$	-	-	100	nA
		$V_R = 60 \text{ V}; T_j = 150 ^{\circ}\text{C}$	-	-	100	μΑ
		V _R = 120 V	[2] _	-	100	nA
		$V_R = 120 \text{ V}; T_j = 150 ^{\circ}\text{C}$	[2] _	-	100	μΑ
C_d	diode capacitance	$f = 1 MHz; V_R = 0 V$	-	-	2.5	pF
t _{rr}	reverse recovery time		[3]	-	6	ns
V_{FR}	forward recovery voltage		<u>[4]</u> _	-	2	V
			[5] _	-	1.5	V

^[1] $T_{amb} = 25$ °C; device has reached the thermal equilibrium when mounted on an FR4 PCB.

^[2] Series connection.

^[3] When switched from I_F = 400 mA to I_R = 400 mA; R_L = 100 Ω ; measured at I_R = 40 mA.

^[4] When switched from $I_F = 400 \text{ mA}$; $t_r = 30 \text{ ns}$.

^[5] When switched from $I_F = 400 \text{ mA}$; $t_r = 100 \text{ ns}$.

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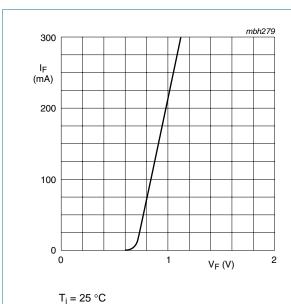
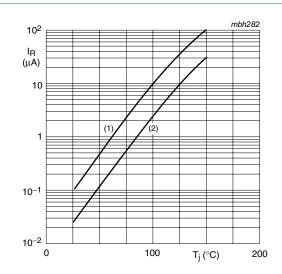


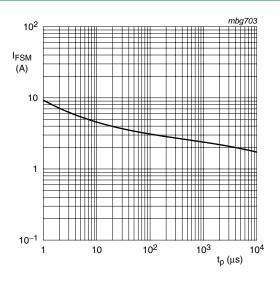
Fig 1. Forward current as a function of forward voltage; typical values



(1) $V_R = 60 \text{ V}$; maximum values

(2) $V_R = 60 \text{ V}$; typical values

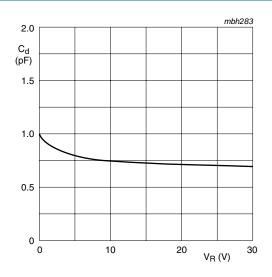
Fig 3. Reverse current as a function of junction temperature



Based on square wave currents.

 T_j = 25 °C; prior to surge

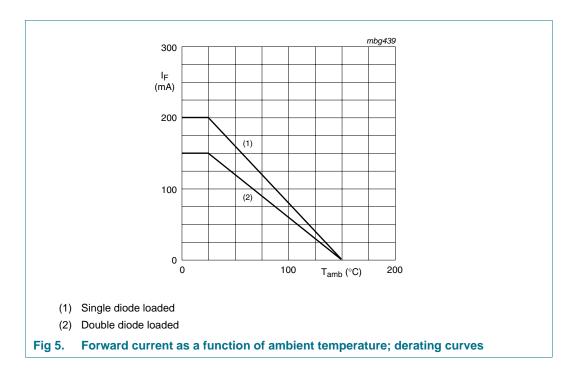
Fig 2. Non-repetitive peak forward current as a function of pulse duration



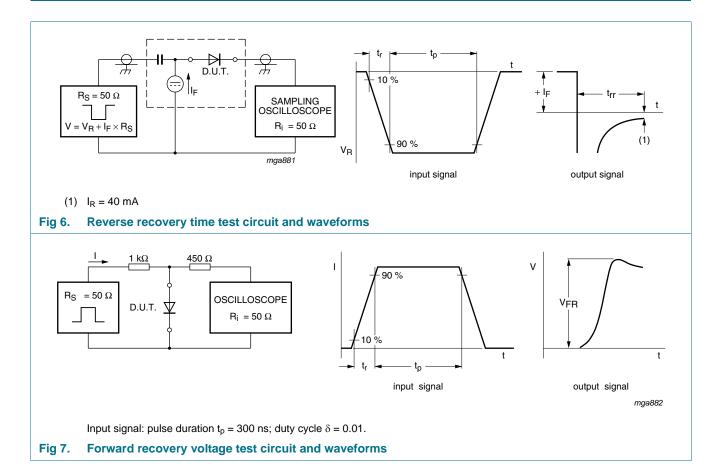
 $f = 1 \text{ MHz}; T_j = 25 \text{ }^{\circ}\text{C}$

Fig 4. Diode capacitance as a function of reverse voltage; typical values

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8. Test information

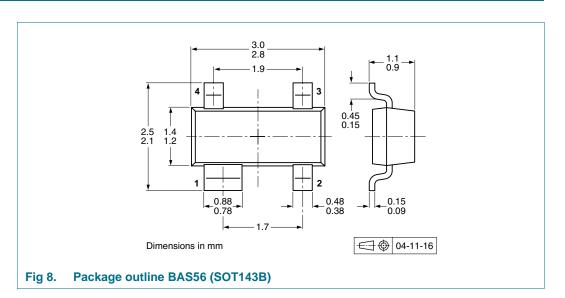


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8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline



10. Packing information

Table 8. Packing methods

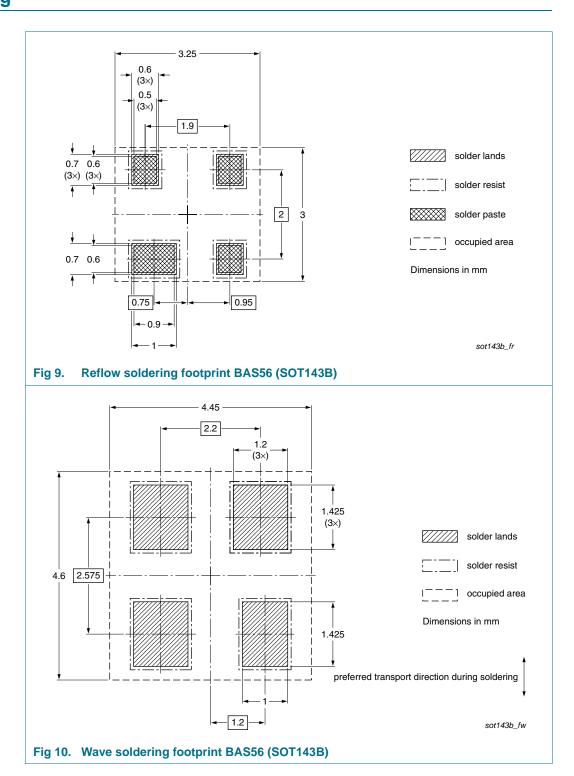
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity	
			3000	10000
BAS56	SOT143B	4 mm pitch, 8 mm tape and reel	-215	-235

^[1] For further information and the availability of packing methods, see Section 14.

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11. Soldering



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12. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
BAS56 v.3	20100629	Product data sheet	-	BAS56_2			
Modifications:		of this data sheet has been of NXP Semiconductors.	redesigned to comply w	vith the new identity			
	 Legal texts have been adapted to the new company name where appropriate. 						
	 Section 1.1 "General description": amended 						
	Section 4 "Marking": updated						
	Table 1 "Quick reference data": added						
	Section 8 "Test information": added						
	• Figure 8: superseded by minimized package outline drawing						
	Section 10 "Packing information": added						
	Section 11 "Soldering": added						
	Section 13	"Legal information": update	d				
BAS56_2	19960910	Product specification	-	BAS56_1			
BAS56_1	19960423	Product specification	-	-			

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13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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BAS56

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14. Contact information

For more information, please visit: http://www.nxp.com

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